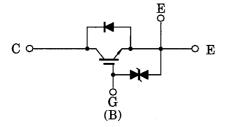
TOSHIBA GTR Module Silicon N Channel IGBT

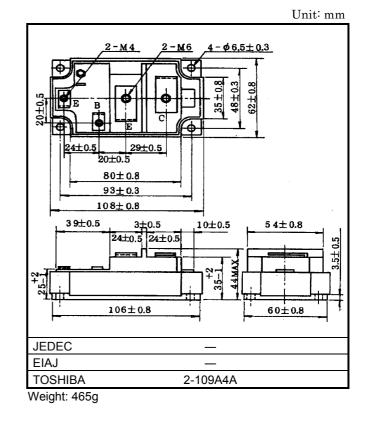
MG400Q1US41

High Power Switching Applications Motor Control Applications

- High input impedance
- High speed : $t_f = 0.5 \mu s$ (Max.) $t_{rr} = 0.5 \mu s$ (Max.)
- Low saturation voltage
 - $: V_{CE(sat)} = 4.0V (Max.)$
- Enhancement-mode
- The electrodes are isolated from case.

Equivalent Circuit





Maximum Ratings (Ta = 25°C)

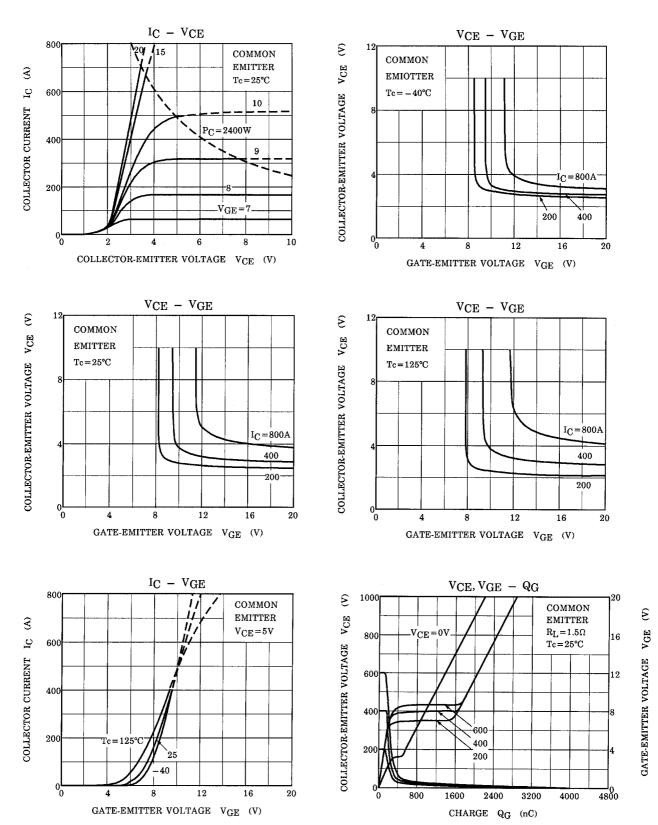
Characteristic		Symbol	Rating	Unit	
Collector-emitter voltage		V _{CES}	1200	V	
Gate-emitter voltage		V _{GES}	±20	V	
Collector current	DC	Ι _C	400	A	
	1ms	I _{CP}	800		
Forward current	DC	١ _F	400	A	
	1ms	I _{FM}	800		
Collector power dissipation (Tc = 25°C)		P _C	2400	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-40 ~ 125	°C	
Isolation voltage		V _{Isol}	2500 (AC 1 minute)	V	
Screw torque (Terminal : M4 / M6 / mounting)		—	2/3/3	N∙m	

Electrical Characteristics (Ta = 25°C)

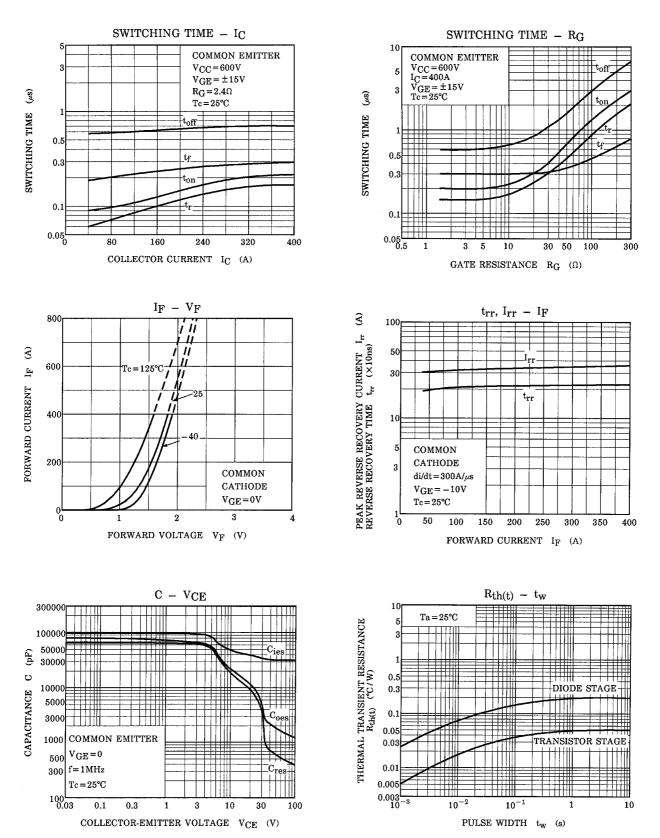
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GES}	$V_{GE} = \pm 20V, V_{CE} = 0$	_	—	±40	μA
Collector cut-off current		ICES	V _{CE} = 1200V, V _{GE} = 0	_	_	4	mA
Gate-emitter cut-off voltage		V _{GE (OFF)}	I _C = 400mA, V _{CE} = 5V	3.0	_	6.0	V
Collector-emitter saturation voltage $V_{CE (sat)}$ $I_C = 400A, V_{CE (sat)}$		I _C = 400A, V _{GE} = 15V	_	3.0	4.0	V	
Input capacitance		C _{ies}	V _{CE} = 10V, V _{GE} = 0, f = 1MHz	_	48000	-	pF
Switching time	Rise time	tr	$15V_{0}$	_	0.3	0.6	μs
	Turn-on time	t _{on}		_	0.4	0.8	
	Fall time	t _f		_	0.2	0.5	
	Turn-off time	t _{off}		_	0.8	1.5	
Forward voltage		V _F		_	2.0	3.0	V
Reverse recovery time		t _{rr}	I _F = 400 A, V _{GE} = −10 V,P di / dt = 300 A / μs	_	0.25	0.5	μs
Thermal resistance		R _{th (j-c)}	Transistor	_	_	0.052	°C/W
			Diode	_	—	0.2	

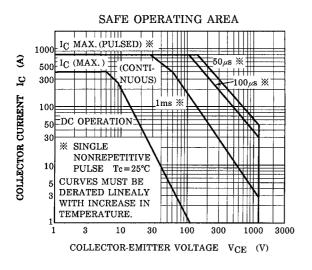
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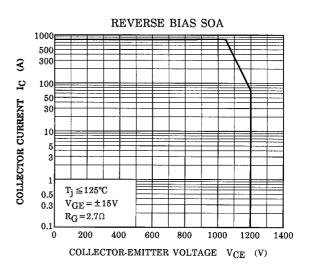
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